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FDMC86012 N-Channel Power Trench[®] MOSFET 30 V, 88 A, 2.7 m Ω

Features

- Max $r_{DS(on)}$ = 2.7 m Ω at V_{GS} = 4.5 V, I_D = 23 A
- Max $r_{DS(on)}$ = 4.7 m Ω at V_{GS} = 2.5 V, I_D = 17.5 A
- High performance technology for extremely low r_{DS(on)}
- Termination is Lead-free
- 100% UIL Tested
- RoHS Compliant

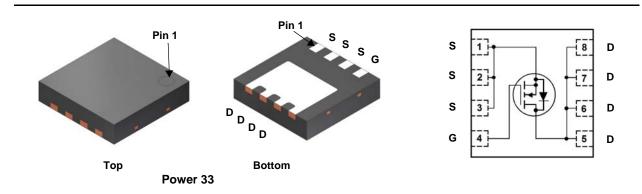


General Description

This device has been designed specifically to improve the efficiency of DC/DC converters. Using new techniques in MOSFET construction, the various components of gate charge and capacitance have been optimized to reduce switching losses. Low gate resistance and very low Miller charge enable excellent performance with both adaptive and fixed dead time gate drive circuits. Very low $r_{DS(on)}$ has been maintained to provide a sub logic-level device.

Applications

- 3.3 V input synchronous buck switch
- Synchronous rectifier



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source \	/oltage			30	V
V _{GS}	Gate to Source V	oltage			±12	V
	Drain Current	-Continuous	T _C = 25 °C		88	
ID	-Continuous		T _A = 25 °C	(Note 1a)	23	A
		-Pulsed		(Note 4)	230	
E _{AS}	Single Pulse Ava	lanche Energy		(Note 3)	337	mJ
P _D	Power Dissipation		T _C = 25 °C		54	W
	Power Dissipation	า	T _A = 25 °C	(Note 1a)	2.3	
T _J , T _{STG}	Operating and Storage Junction Temperature Range				-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	2.3	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1a)	53	0/10

Package Marking and Ordering Information

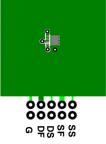
Device Marking Device		Package	Reel Size	Tape Width	Quantity	
FDMC86012	FDMC86012	Power33	13 "	12 mm	3000 units	

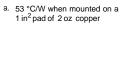
October 2012

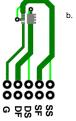
FDMC86012 N
N-Channel I
Power Trench [®]
MOSFET

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, V_{GS} = 0 \ V$	30			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		43		mV/°C	
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$			1	μΑ	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA	
On Chara	octeristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	0.8	1.0	1.5	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-4		mV/°C	
r _{DS(on)}		$V_{GS} = 4.5 \text{ V}, I_D = 23 \text{ A}$		2.2	2.7		
	Static Drain to Source On Resistance	V _{GS} = 2.5 V, I _D = 17.5 A		3.4	4.7	mΩ	
		$V_{GS} = 4.5 \text{ V}, \ I_D = 23 \text{ A}, \ T_J = 125 \text{ °C}$		3.5	4.3		
9 _{FS}	Forward Transconductance	V _{DD} = 5 V, I _D = 23 A		144		S	
Dynamic	Characteristics						
C _{iss}	Input Capacitance			3625	5075	pF	
C _{oss}	Output Capacitance	─ V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		1230	1725	pF	
C _{rss}	Reverse Transfer Capacitance			185	260	pF	
R _g	Gate Resistance		0.1	0.9	3.0	Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			20	32	ns	
t _r	Rise Time	V _{DD} = 15 V, I _D = 23 A,		11	20	ns	
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		43	69	ns	
t _f	Fall Time			8	16	ns	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V$ to 4.5 V		27	38	nC	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0$ V to 2.5 V $V_{DD} = 15$ V,		16	23	nC	
Q _{gs}	Gate to Source Charge	I _D = 23 A		5.8		nC	
Q _{gd}	Gate to Drain "Miller" Charge			5.4		nC	
Drain-So	urce Diode Characteristics						
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 23 A$ (Note 2)		0.8	1.3	V	
• 50		$V_{GS} = 0 V, I_S = 1.9 A$ (Note 2)		0.7	1.2	V	
t _{rr}	Reverse Recovery Time $I_F = 23 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$			40	64	ns	
Q _{rr}	Reverse Recovery Charge			23	37	nC	







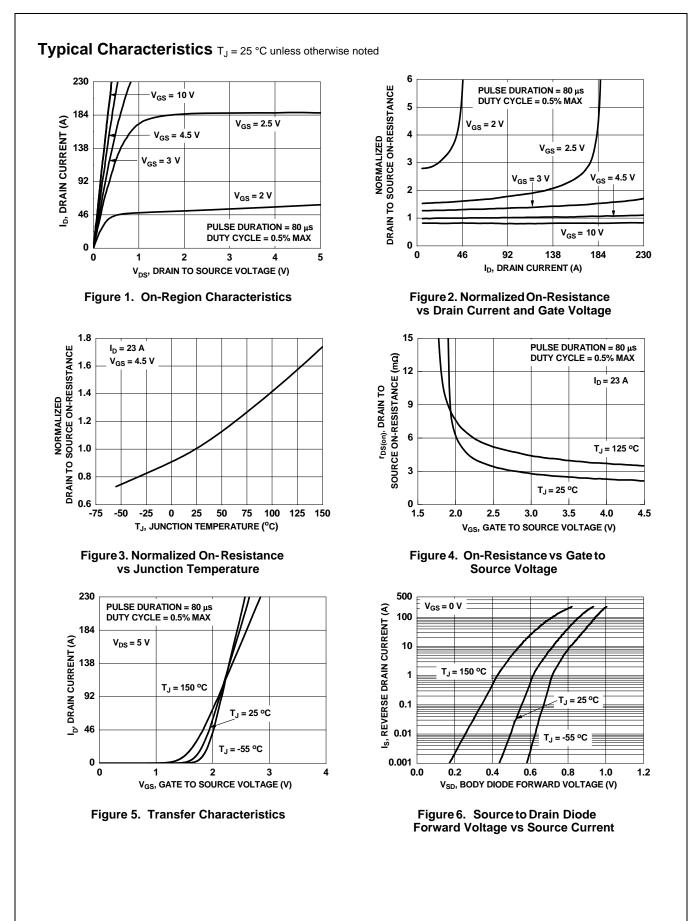
b. 125 °C/W when mounted on a

minimum pad of 2 oz copper

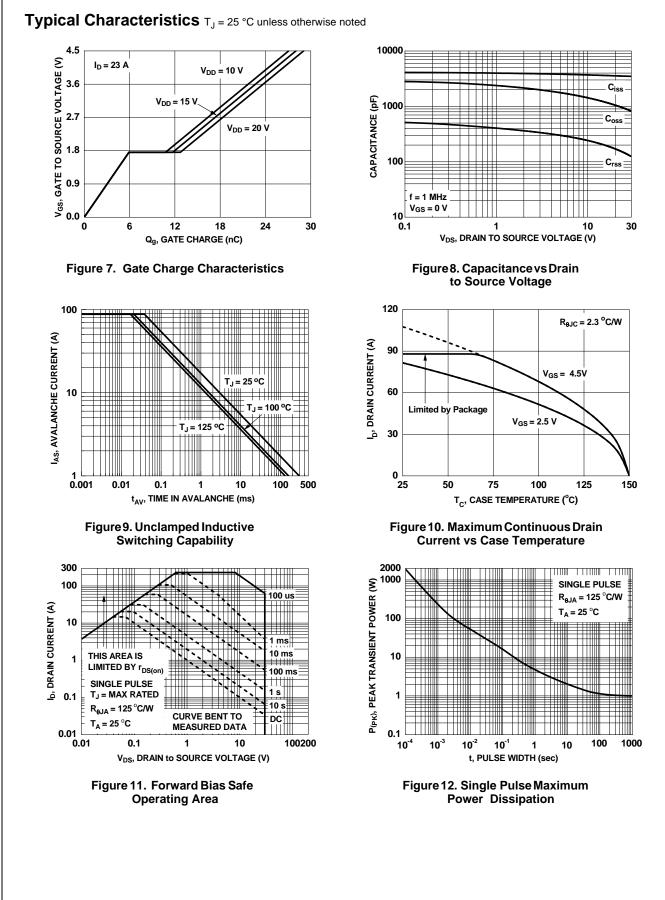
2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

3. EAS of 337 mJ is based on starting TJ = 25 °C; N-ch: L = 3 mH, IAS = 15 A, VDD = 30 V, VGS = 10 V. 100% test at L = 0.3 mH, IAS = 33 A.

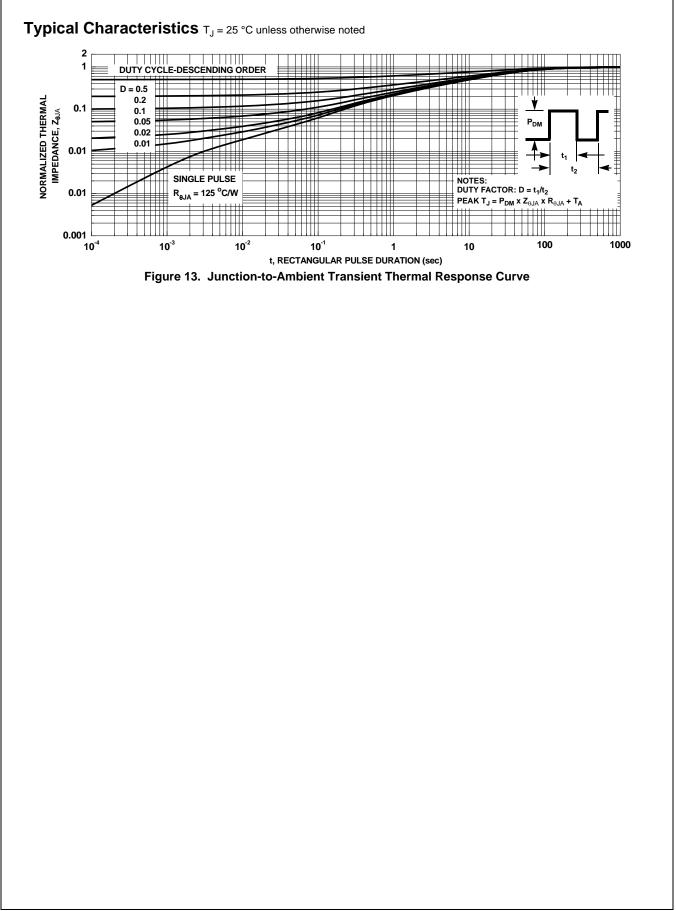
4. Pulsed Id limited by junction temperature,td<=100uS, please refer to SOA curve for more details.



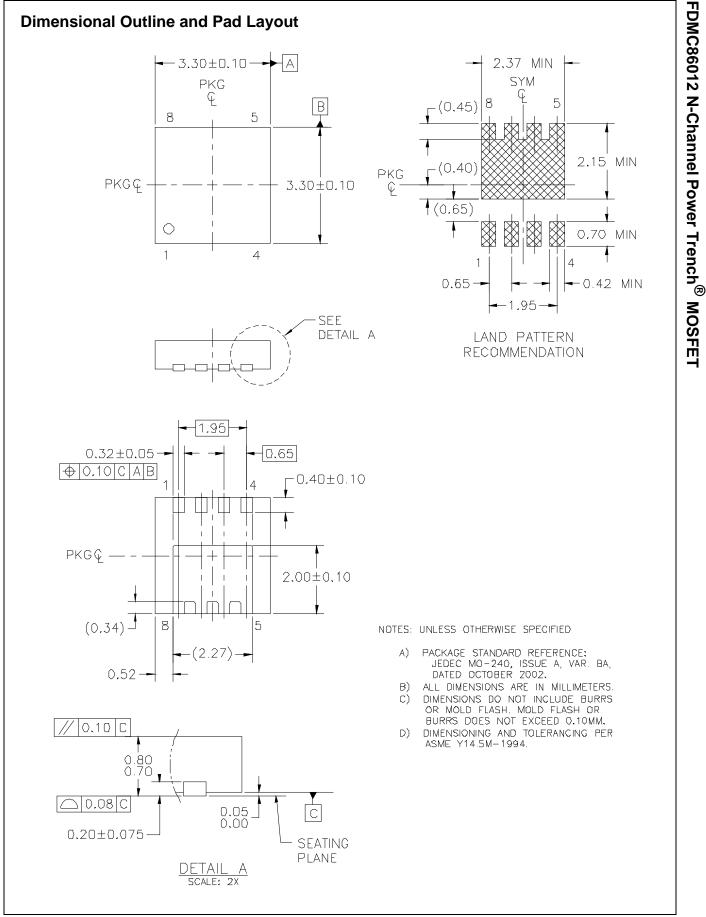




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FDMC86012 N-Channel Power Trench[®] MOSFET





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